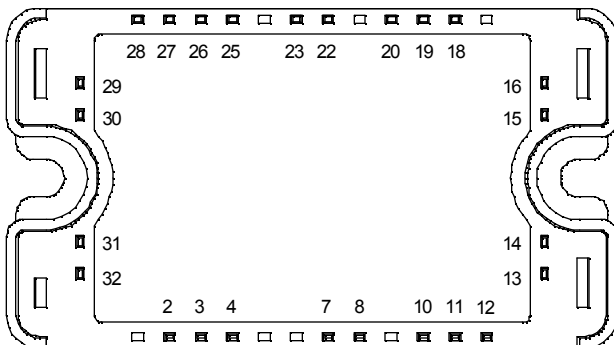
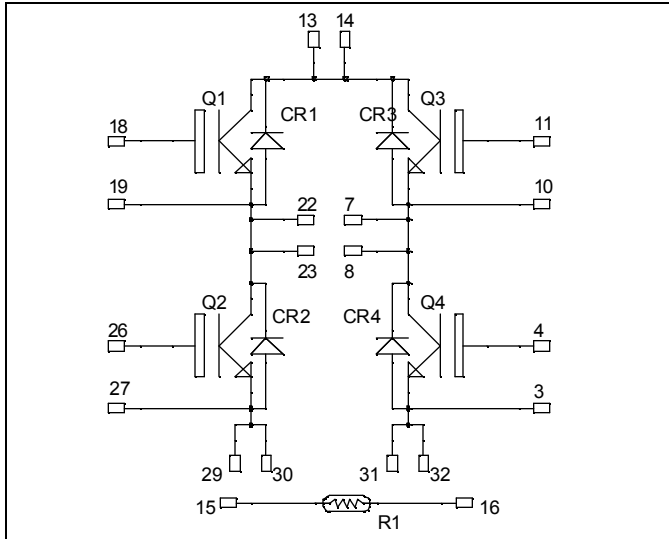


**Full - Bridge
PT IGBT Power Module**

**$V_{CES} = 600V$
 $I_C = 15A @ T_c = 80^\circ C$**



All multiple inputs and outputs must be shorted together
Example: 13/14 ; 29/30 ; 22/23 ...

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] Punch Through (PT) IGBT
 - Low conduction loss
 - Ultra fast tail current shutoff
 - Low gate charge
 - Switching frequency capability in the 200kHz range
 - Soft recovery parallel diodes
 - Low diode VF
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage	600	V
I_C	Continuous Collector Current	$T_c = 25^\circ C$ 25 $T_c = 80^\circ C$ 15	A
I_{CM}	Pulsed Collector Current	$T_c = 25^\circ C$ 60	
V_{GE}	Gate - Emitter Voltage	± 20	V
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$ 83	W
SSOA	Switching Safe Operating Area	$T_j = 150^\circ C$ 65A @ 600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
BV_{CES}	Collector - Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 250\mu A$	600			V
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V$ $V_{CE} = 600V$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$		250 2500	μA
$V_{CE(on)}$	Collector Emitter on Voltage	$V_{GE} = 15V$ $I_C = 15A$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	2.2 2.1	2.7	V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1mA$	3		6	V
I_{GES}	Gate - Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$			± 100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V$		1685		pF
C_{oes}	Output Capacitance	$V_{CE} = 25V$		210		
C_{res}	Reverse Transfer Capacitance	$f = 1MHz$		15		
Q_g	Total gate Charge	$V_{GE} = 15V$		55		nC
Q_{ge}	Gate - Emitter Charge	$V_{Bus} = 300V$		12		
Q_{gc}	Gate - Collector Charge	$I_C = 15A$		15		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 15A$ $R_G = 5\Omega$		8		ns
T_r	Rise Time			12		
$T_{d(off)}$	Turn-off Delay Time			29		
T_f	Fall Time			58		
E_{on1}	Turn-on Switching Energy			130		μJ
E_{on2}	Turn-on Switching Energy ❶			152		
E_{off}	Turn-off Switching Energy ❷			121		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 15A$ $R_G = 5\Omega$		8		ns
T_r	Rise Time			12		
$T_{d(off)}$	Turn-off Delay Time			69		
T_f	Fall Time			88		
E_{on1}	Turn-on Switching Energy			130		μJ
E_{on2}	Turn-on Switching Energy ❶			267		
E_{off}	Turn-off Switching Energy ❷			268		

❶ E_{on2} includes diode reverse recovery

❷ In accordance with JEDEC standard JESD24-1

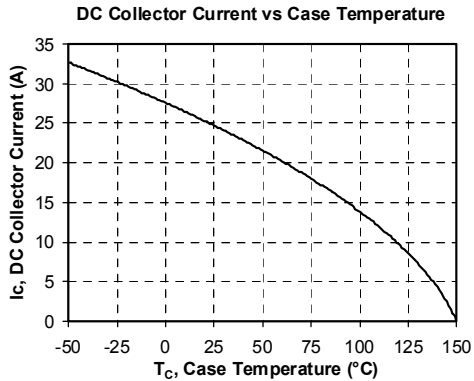
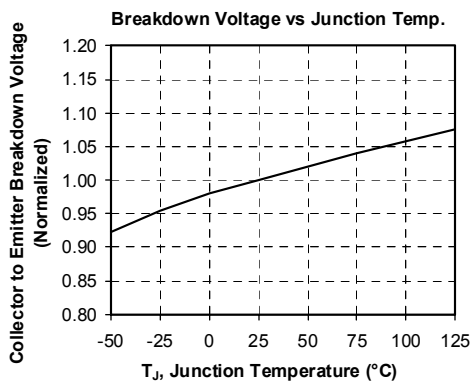
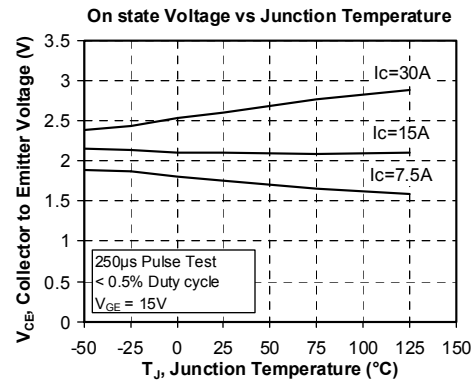
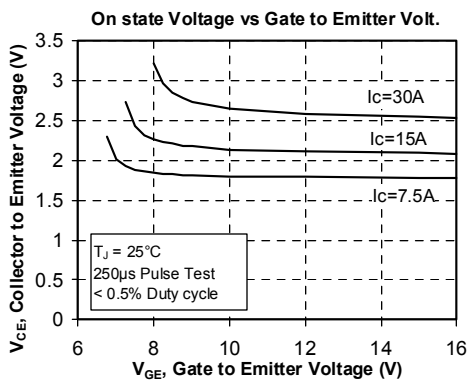
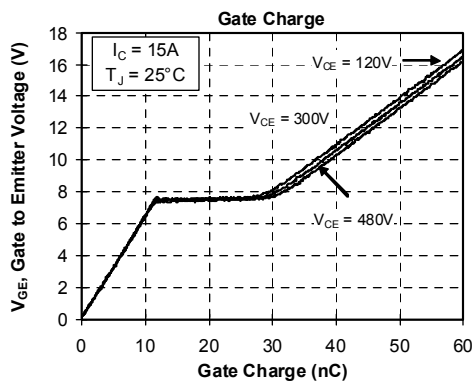
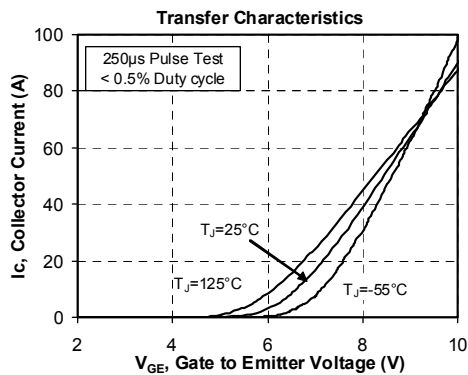
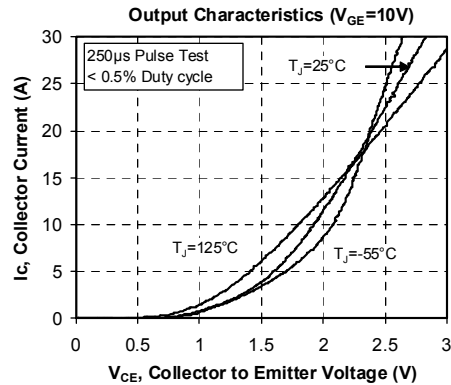
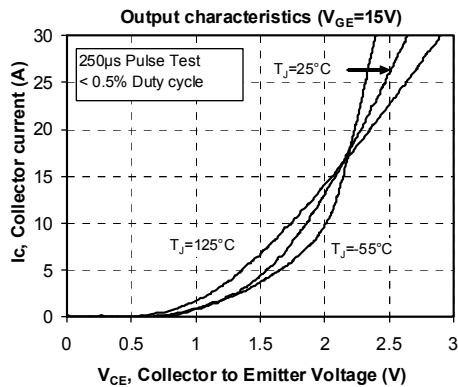
Temperature sensor NTC

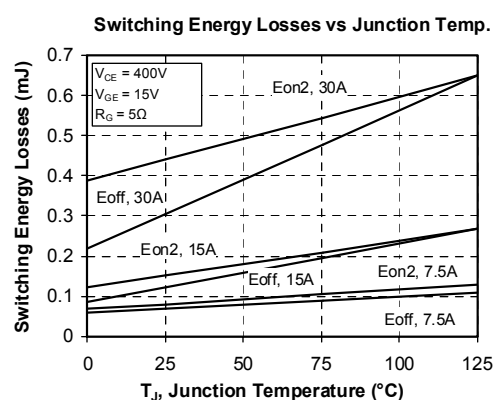
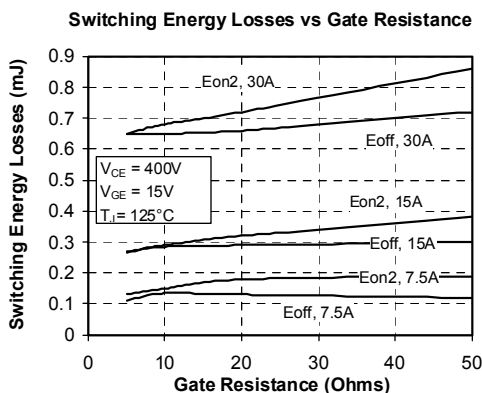
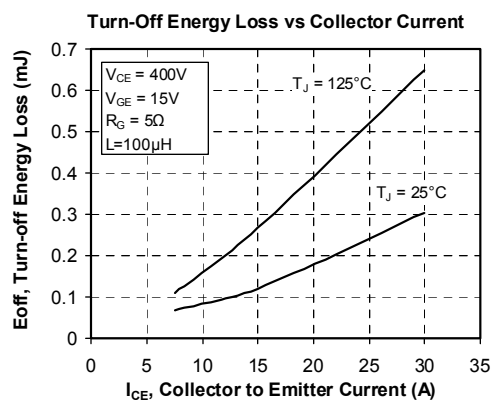
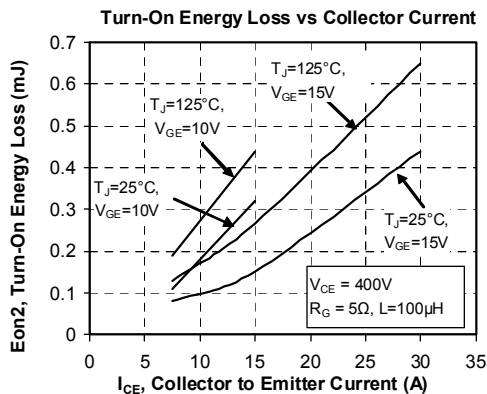
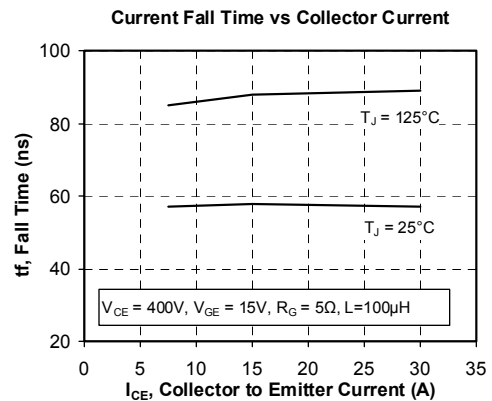
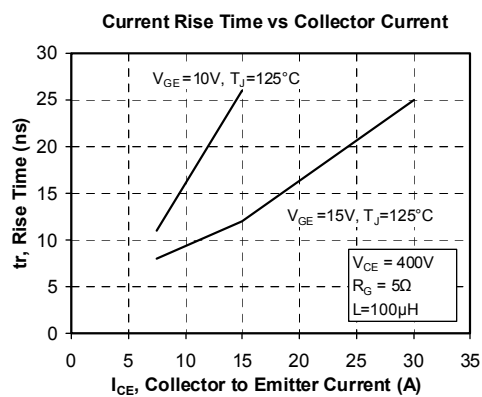
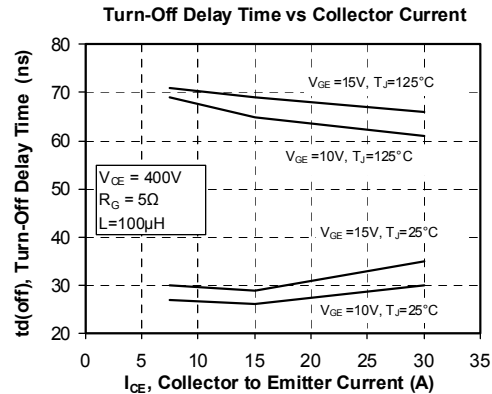
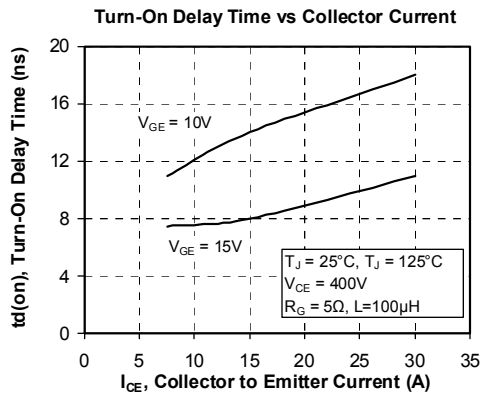
Symbol	Characteristic	Min	Typ	Max	Unit
R_{25}	Resistance @ 25°C		68		$k\Omega$
$B_{25/85}$	$T_{25} = 298.16\text{ K}$		4080		K

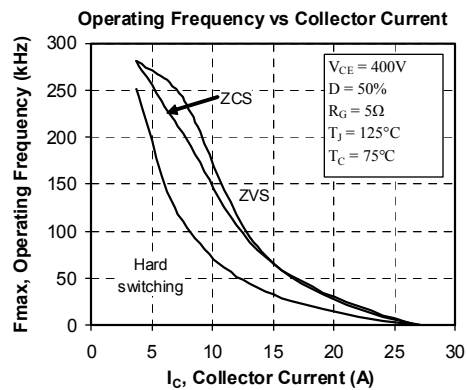
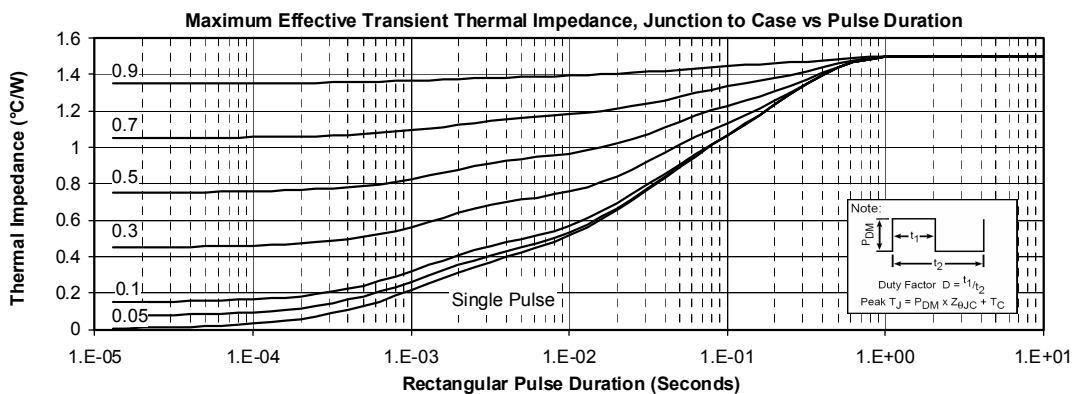
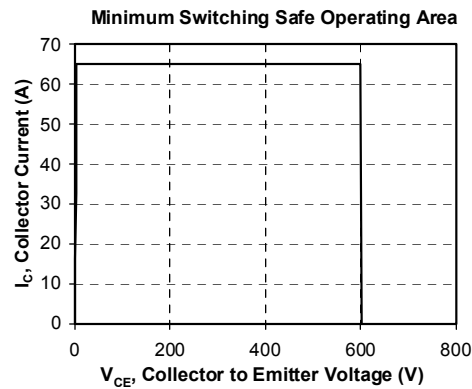
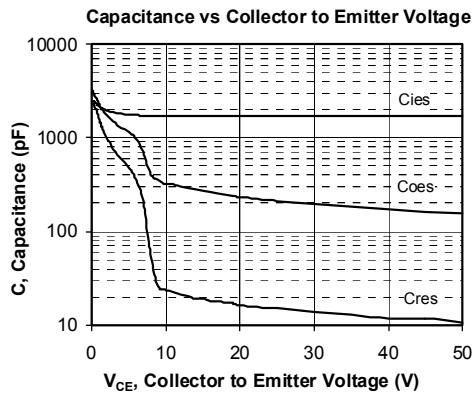
$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$

T: Thermistor temperature
R_T: Thermistor value at T

Typical Performance Curve







APT reserves the right to change, without notice, the specifications and information contained herein

APT's products are covered by one or more of U.S. patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S. and Foreign patents pending. All Rights Reserved.